

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



### Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



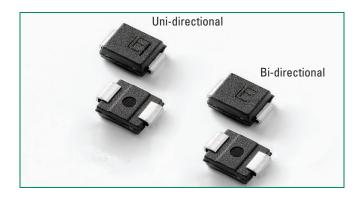






### **TPSMB Series**





### **Agency Approvals**

AGENCY	AGENCY FILE NUMBER
<i>I</i> R <sub>®</sub>	E230531

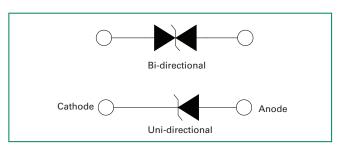
### Maximum Ratings and Thermal Characteristics ( $T_A$ =25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at $T_A$ =25°C by 10/1000 $\mu$ s waveform (Fig.1)(Note 1), (Note 2)	P <sub>PPM</sub>	600	W
Power Dissipation on infinite heat sink at $T_A = 50^{\circ}C$	P <sub>M(AV)</sub>	5.0	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I <sub>FSM</sub>	100	А
Maximum Instantaneous Forward Voltage at 50A for Unidirectional only	V <sub>F</sub>	3.5V	V
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to 175	°C
Typical Thermal Resistance Junction to Lead	R <sub>uJL</sub>	20	°C/W
Typical Thermal Resistance Junction to Ambient	R <sub>uJA</sub>	100	°C/W

#### Notes:

- 1. Non-repetitive current pulse , per Fig. 3 and derated above  $\rm T_A = 25^{o}C$  per Fig. 2.
- 2. Mounted on copper pad area of 0.2x0.2" (5.0 x 5.0mm) to each terminal.
- Measured on 8.3ms single half sine wave or equivalent square wave for unidirectional device only,duty cycle=4 per minute maximum.

### **Functional Diagram**



### **Description**

The TPSMB series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

### **Features**

- Hi reliability application and automotive grade AEC Q101 qualified
- For surface mounted applications to optimize board space
- Low profile package
- Typical failure mode is short from over-specified voltage or current
- Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- IEC-61000-4-2 ESD 15kV(Air), 8kV (Contact)
- ESD protection of data lines in accordance with IEC 61000-4-2 (IEC801-2)
- EFT protection of data lines in accordance with IEC 61000-4-4 (IEC801-4)
- $V_{BR} @T_J = V_{BR} @25^{\circ}C \times (1 + \alpha T \times (T_J 25))$

(  $\alpha$  T:Temperature Coefficient)

Glass passivated chip junction

- 600W peak pulse power capability at 10/1000µs waveform, repetition rate (duty cycles):0.01%
- Fast response time: typically less than 1.0ns from 0V to BV min
- Excellent clamping capability
- Low incremental surge resistance
- Typical I<sub>R</sub> less than 1µA above 12V
- High temperature soldering guaranteed: 260°C/10 seconds at terminals
- Plastic package has underwriters laboratory flammability 94V-O
- Meet MSL level1, per J-STD-020, LF maximun peak of 260°C
- Matte tin lead–free plated
- Halogen free and RoHS compliant
- 2nd level interconnect is Pb-free per IPC/JEDEC J-STD-609A.01

### **Applications**

TVS devices are ideal for the protection of I/O Interfaces,  $V_{\rm cc}$  bus and other vulnerable circuits used in Automotive applications.

TPSMB Series

1 ©2014 Littelfuse, Inc.
Specifications are subject to change without notice.



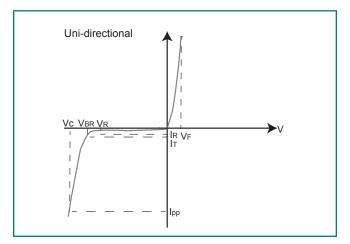
# Transient Voltage Suppression Diodes Surface Mount – 600W > TPSMB series

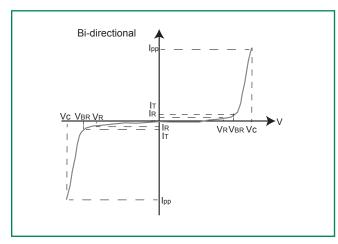
### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Part Number (Uni)	Part Number (Bi)	Mar	king	Typical I <sub>R</sub> @ 150°C (µA)	Reverse Stand off Voltage V <sub>R</sub> (Volts)		down ge V <sub>BR</sub> s) @ I <sub>T</sub>	Test Current I <sub>T</sub> (mA)	Maximum Clamping Voltage V <sub>c</sub> @ I (V)	Maximum Peak Pulse Current I <sub>pp</sub> (A)	Reverse Leakage L	Agency Approval
		UNI	ВІ			MIN	MAX					
TPSMB13.	A TPSMB13CA	13AA	13CA	8	11.10	12.40	13.70	1	18.2	33.5	1	X
TPSMB15.	A TPSMB15CA	15AA	15CA	8	12.80	14.30	15.80	1	21.2	28.8	1	X
TPSMB16.	A TPSMB16CA	16AA	16CA	8	13.60	15.20	16.80	1	22.5	27.1	1	X
TPSMB18.	A TPSMB18CA	18AA	18CA	8	15.30	17.10	18.90	1	25.5	24.2	1	X
TPSMB20	A TPSMB20CA	20AA	20CA	8	17.10	19.00	21.00	1	27.7	22.0	1	X
TPSMB22	A TPSMB22CA	22AA	22CA	8	18.80	20.90	23.10	1	30.6	19.9	1	X
TPSMB24	A TPSMB24CA	24AA	24CA	8	20.50	22.80	25.20	1	33.2	18.4	1	X
TPSMB27	A TPSMB27CA	27AA	27CA	8	23.10	25.70	28.40	1	37.5	16.3	1	X
TPSMB30	A TPSMB30CA	30AA	30CA	8	25.60	28.50	31.50	1	41.4	14.7	1	X
TPSMB33	A TPSMB33CA	33AA	33CA	8	28.20	31.40	34.70	1	45.7	13.3	1	X
TPSMB36	A TPSMB36CA	36AA	36CA	8	30.80	34.20	37.80	1	49.9	12.2	1	X
TPSMB39	A TPSMB39CA	39AA	39CA	8	33.30	37.10	41.00	1	53.9	11.3	1	X
TPSMB43.	A TPSMB43CA	43AA	43CA	8	36.80	40.90	45.20	1	59.3	10.3	1	X
TPSMB47	A TPSMB47CA	47AA	47CA	8	40.20	44.70	49.40	1	64.8	9.4	1	X
TPSMB51.	A TPSMB51CA	51AA	51CA	8	43.60	48.50	53.60	1	70.1	8.7	1	X
TPSMB56	A TPSMB56CA	56AA	56CA	8	47.80	53.20	58.80	1	77.0	7.9	1	X
TPSMB62	A TPSMB62CA	62AA	62CA	8	53.00	58.90	65.10	1	85.0	7.2	1	X
TPSMB68	A TPSMB68CA	68AA	68CA	8	58.10	64.60	71.40	1	92.0	6.6	1	X
TPSMB75	A TPSMB75CA	75AA	75CA	8	64.10	71.30	78.80	1	103.0	5.9	1	X
TPSMB82	A TPSMB82CA	82AA	82CA	8	70.10	77.90	86.10	1	113.0	5.4	1	X
TPSMB91.	A TPSMB91CA	91AA	91CA	8	77.80	86.50	95.50	1	125.0	4.9	1	X



### **I-V Curve Characteristics**





- $P_{\tiny{PPM}}$  Peak Pulse Power Dissipation Max power dissipation
- ${f V_{_R}}$  **Stand-off Voltage** Maximum voltage that can be applied to the TVS without operation
- V<sub>BR</sub> Breakdown Voltage Maximum voltage that flows though the TVS at a specified test current (I,)
- V<sub>c</sub> Clamping Voltage Peak voltage measured across the suppressor at a specified Ippm (peak impulse current)
- $I_{R}$  Reverse Leakage Current -- Current measured at  $V_{R}$
- V, Forward Voltage Drop for Uni-directional

### Ratings and Characteristic Curves (T<sub>A</sub>=25°C unless otherwise noted)

Figure 1 - TVS Transients Clamping Waveform

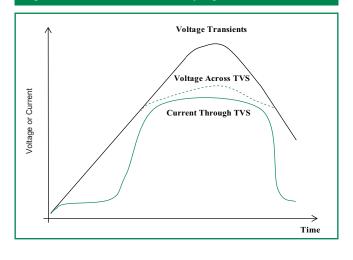
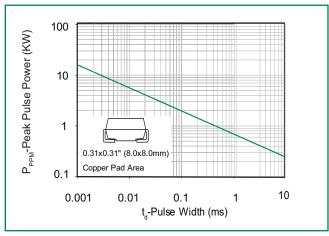


Figure 2 - Peak Pulse Power Rating Curve



continues on next page.

Ratings and Characteristic Curves (T<sub>a</sub>=25°C unless otherwise noted) (Continued)

Figure 3 - Peak Pulse Power or Current Derating Curve vs Initial Junction Temperature

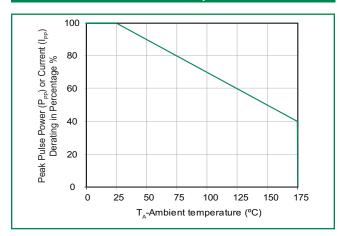


Figure 5 - Typical Junction Capacitance

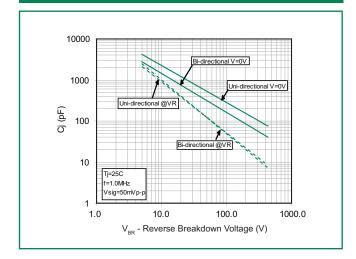


Figure 4 - Pulse Waveform

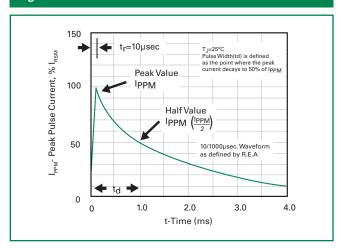
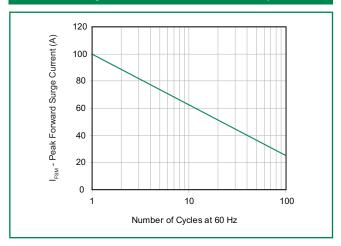


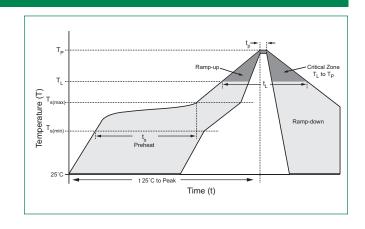
Figure 6 - Maximum Non-Repetitive Peak Forward **Surge Current Uni-Directional Only** 



## **Transient Voltage Suppression Diodes**Surface Mount – 600W > TPSMB series

### **Soldering Parameters**

Reflow Cor	ndition	Lead-free assembly		
	-Temperature Min (T <sub>s(min)</sub> )	150°C		
Pre Heat	-Temperature Max (T <sub>s(max)</sub> )	200°C		
	-Time (min to max) (t <sub>s</sub> )	60 – 120 secs		
Average ra to peak	mp up rate (Liquidus Temp (T <sub>L</sub> )	3°C/second max		
$T_{S(max)}$ to $T_{L}$	- Ramp-up Rate	3°C/second max		
Reflow	-Temperature (T <sub>L</sub> ) (Liquidus)	217°C		
	-Time (min to max) (t <sub>s</sub> )	60 – 150 seconds		
Peak Temp	erature (T <sub>P</sub> )	260 <sup>+0/-5</sup> °C		
Time within	n 5°C of actual peak re (t <sub>p</sub> )	30 seconds max		
Ramp-dow	n Rate	6°C/second max		
Time 25°C	to peak Temperature (T <sub>P</sub> )	8 minutes max.		
Do not exc	eed	280°C		



### **Physical Specifications**

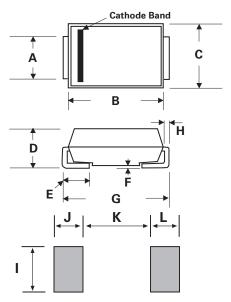
Weight	0.003 ounce, 0.093 grams
Case	JEDEC DO214AA. Molded plastic body over glass passivated junction
Polarity	Color band denotes cathode except Bidirectional.
Terminal	Matte Tin-plated leads, Solderable per JESD22-B102

### **Environmental Specifications**

High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Temperature Cycling	JESD22-A104
MSL	JEDEC-J-STD-020, Level 1
H3TRB	JESD22-A101
RSH	JESD22-B106

### **Dimensions**

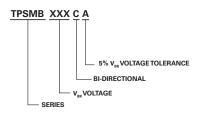
### DO-214AA (SMB J-Bend)



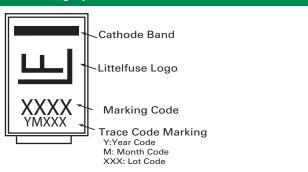
Dimensions	Incl	hes	Millimeters		
Dimensions	Min	Max	Min	Max	
А	0.077	0.086	1.950	2.200	
В	0.160	0.180	4.060	4.570	
С	0.130	0.155	3.300	3.940	
D	0.084	0.096	2.130	2.440	
Е	0.030	0.060	0.760	1.520	
F	-	0.008	-	0.203	
G	0.205	0.220	5.210	5.590	
Н	0.006	0.012	0.152	0.305	
1	0.089	-	2.260	-	
J	0.085	-	2.160	-	
K	-	0.107	-	2.740	
L	0.085	-	2.160	-	

## **Transient Voltage Suppression Diodes**Surface Mount – 600W > TPSMB series

### **Part Numbering System**



### Part Marking System



### **Packaging**

Part number	Component Package	Quantity	Packaging Option	Packaging Specification
TPSMBxxxXX	DO-214AA	3000	Tape & Reel - 12mm tape/13" reel	EIA STD RS-481

### **Tape and Reel Specification**

